

50A SILICON POWER RECTIFIER DIODE

Description

The BYY57A/58A are hermetically sealed 50A- The diodes can be delivered with limited forward diodes, which are available in different reverse voltage classes up to 800V.

and reverse current differences for parallel connecting in rectifier stacks and backoff-diodes

Features

- Forward current 50A
- Reverse voltage 75V 800V
- Hermetic press-fit package
- · Available in different modifications of the
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative.

https://www.diodes.com/quality/product-definitions/

Applications

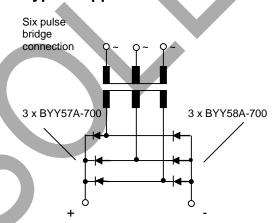
- Power supplies
- Rectifier diode in car generators
- Rectifier bridges/stacks
- Back-off-diodes

Pinout details



BYY57A: 1 - cathode; 2 - anode BYY58A: 1 - anode; 2 - cathode

Typical application circuit



Ordering information

Device	Quantity per box	Options
BYY57A-75;; BYY57A-800	500	The package quantities for the different package
BYY58A-75;; BYY58A-800	500	modifications are included in "PressFitPackageModifications.pdf"

Device marking

Devices are identified by type. Colour of marking: BYY57A- black, BYY58A - red

422	 date code 422 = 2004 week 22
/ ZETEX \	
\ BYY57/	 diode type
\ A400 \	 50A diode / repetitive peak reverse voltage V _{RRM} (in V) 400



Absolute maximum ratings (at T_{amb} = 25°C unless otherwise stated)

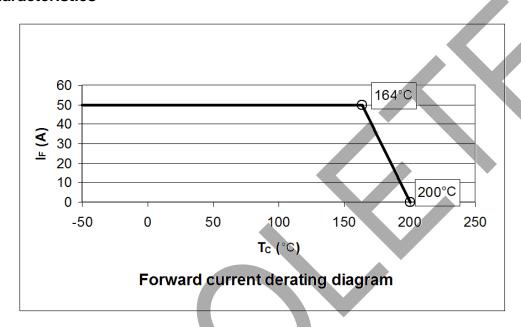
Parameter			Symbol		Unit	Test condition	
	BYY57A-75	BYY58A-75		75			
	BYY57A-100	BYY58A-100		100			
	BYY57A-150	BYY58A-150		150	V		
	BYY57A-200	BYY58A-200		200			
Repetitive peak	BYY57A-300	BYY58A-300	V_{RRM}	300		T _c ± 150°C	
reverse voltage	BYY57A-400	BYY58A-400	VRRM	400			
	BYY57A-500	BYY58A-500		500			
	BYY57A-600	BYY58A-600		600			
	BYY57A-700	BYY58A-700		700			
	BYY57A-800	BYY58A-800		800		•	
Forward cu	rrent, arithmetic	value	I _{FAV}	50	А		
Surge forward current			I _{FSM}	900	A	half-sine wave, ≤ 10 ms T _J = 175°C half-sine wave, ≤ 10 ms	
Maximum rated value		∫i²dt	4050 3200	A²s	half-sine wave, ≤ 10 ms T _J = 175°C half-sine wave, ≤ 10 ms		
Repetitive peak forward current			I _{FRM} =π*I _{FAV}	157	Α	f = >15 Hz	
Effective forward current			I _{FRMS}	78	Α		
Junction temperature			T _{Jmax}	200	°C		
Storage temperature range			T _{stg}	- 50 to + 175	°C		



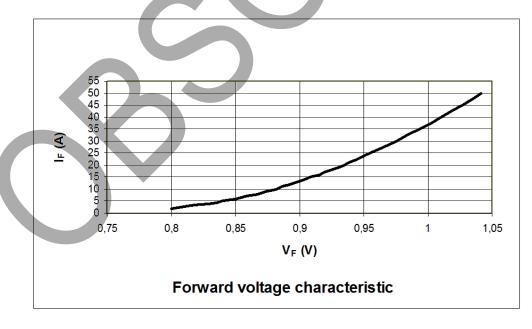
Thermal resistance

Parameter Symbol		Value	Unit		
Junction to case	Rejc	0.8	°C/W		

Thermal characteristics



Electrical characteristics (at T_{amb} = 25°C unless otherwise stated)





Electrical characteristics (at T_{amb} = 25°C unless otherwise stated)

Parameter		Symbol	Min.	Тур.	Max.	Unit	Test conditions	
Forward voltage	BYY57A-75800 BYY58A-75800	VF	-	1.05	1.15	V	I _F = 50 A, measuring time 10ms (half-sine wave)	
Forward voltage	BYY57A-75800 BYY58A-75800	VF	-	0.810	1	٧	I _F = 20 A, measuring time 10ms (half-sine wave),T _J = 150°	
(information values)	BYY57A-75800 BYY58A-75800	V _F	-	,	1.2	V	I _F = 75 A	
	BYY57A-75150 BYY58A-75150		-	-	3	A	T _J = 150°C, at	
Reverse	BYY57A-200800 BYY58A-200800	I _{RRM}	-	-	1.5	mA	VRRM	
current	BYY57A-75400 BYY58A-75400	ı	-	-	0.25	mA	at V _{RRM}	
	BYY57A-500800 BYY58A-500800	I _{RRM}	•	1	0.1	ША	at V RRM	
Threshold voltage (information value)		V _(FO)	-	0.66	-	V	T _J = 175°C	
Slope resistance (information value)		r _F		4.5	-	mΩ	T _J = 175°C	

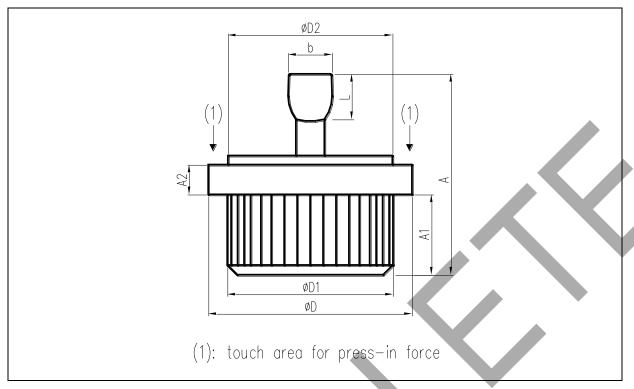
Options: Electrical characteristics for parallel connecting

(at $T_{amb} = 25$ °C unless otherwise stated)

Option	Parameter	Symbol	Min.	Тур.	Max.	Unit	Test conditions
1	Forward voltage difference in one category of forward voltage	ΔV _F		-	0.05	V	I_F = 50 A, measuring time 10ms (half-sine wave)
2	Reverse current in one category of forward voltage (only for BYY57A-300800 and BYY58A-300800)	ĪR	-	-	0.01	mA	at V _{RRM}



Packaging details



Package dimensions

Dimensions in millimeters are control dimensions, dimensions in inches are approximate

DIM		Millimeters			Inches			
	MIN	TYP	MAX	MIN	TYP	MAX		
Α	15,00	15,50	16,00	0,591	0,610	0,630		
A1	5,90	6,10	6,30	0,232	0,240	0,248		
A2	2,10	2,30	2,50	0,083	0,091	0,098		
b	3,50	3,80	4,10	0,138	0,150	0,161		
D	15,50	15,70	15,90	0,610	0,618	0,626		
D1	12,75	12,80	12,85	0,502	0,504	0,506		
D2	12,30	12,50	12,70	0,484	0,492	0,500		
L	3,00	3,50	4,00	0,118	0,138	0,157		



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